

CXA3099N

IF Amplifier for M-ary FSK Pagers

Description

The CXA3099N is a low current consumption FM IF amplifier which employs the newest bipolar process. It is suitable for M-ary FSK pagers.

Features

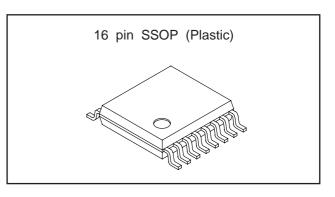
- Low current consumption: 590 μA (typ. at Vcc = 1.4 V)
- Low voltage operation: Vcc = 1.1 to 4.0 V
- Small package 16-pin SSOP
- Needless of IF decoupling capacitor
- Reference power supply for operational amplifier and comparator
- IF input, Vcc standard

Applications

M-ary FSK pagers

Structure

Bipolar silicon monolithic IC



Absolute Maximum Ratings

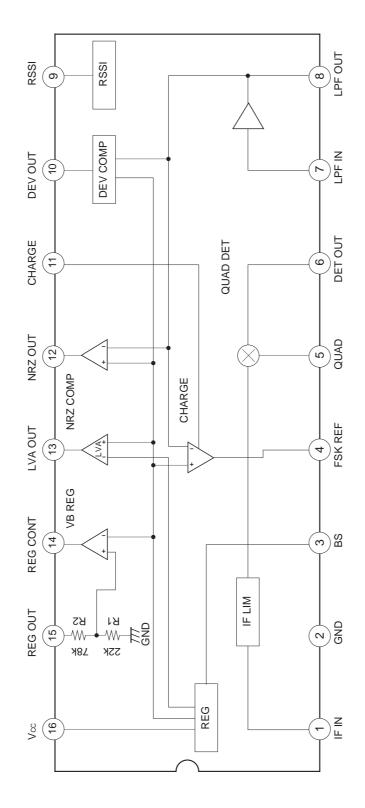
•	Supply voltage	Vcc	7.0	V
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- Operating temperature Topr -20 to +75 °C
- Storage temperature Tstg -65 to +150 °C
- Allowable power dissipation PD 312 mW

Operating Condition

Supply voltage	Vcc1	1.1 to 4.0	V
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Block Diagram and Pin Configuration

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Pin Description

Pin No.	Symbol	Pin voltage	Equivalent circuit	Description
1	IF IN	1.4 V	20k 20k Vcc 1.5k ₹ ₹ 1.5k 1.5k GND	IF limiter amplifier input.
2	GND			Ground.
3	B.S.		3 → ₩ → 40k ≥ 140k ≥ GND	Controls the battery saving. Setting this pin low suspends the operation of IC. (Applied voltage range: –0.5 V to +7.0 V)
4	FSK REF	0.2 V	4 Vcc Vcc Vcc GND	Connects the capacitor that determines the low cut-off frequency for the entire system.
5	QUAD	1.4 V	5 20p GND	Connects the phase shifter of FM detector circuit.
6	DET OUT	0.2V	6 72 GND	FM detector output.

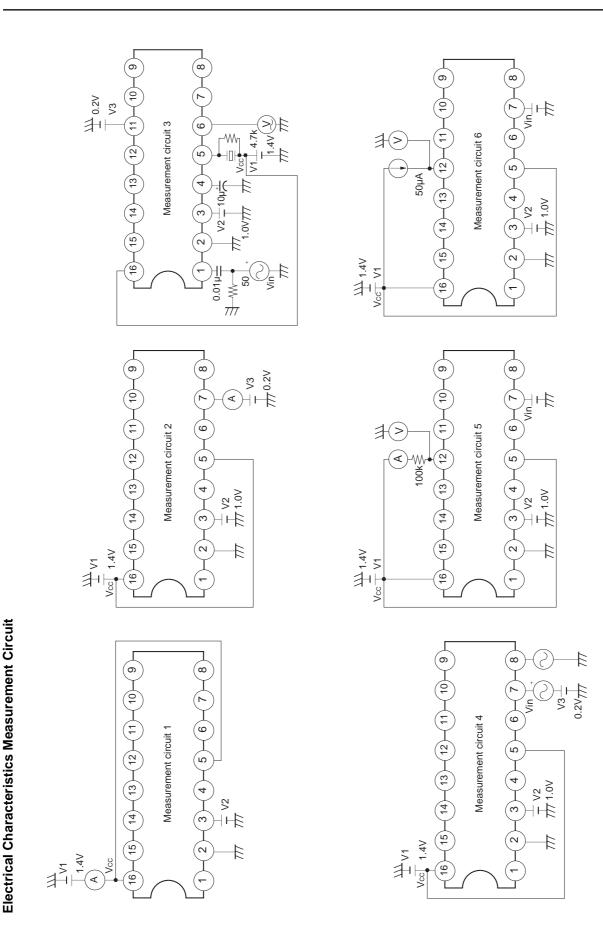
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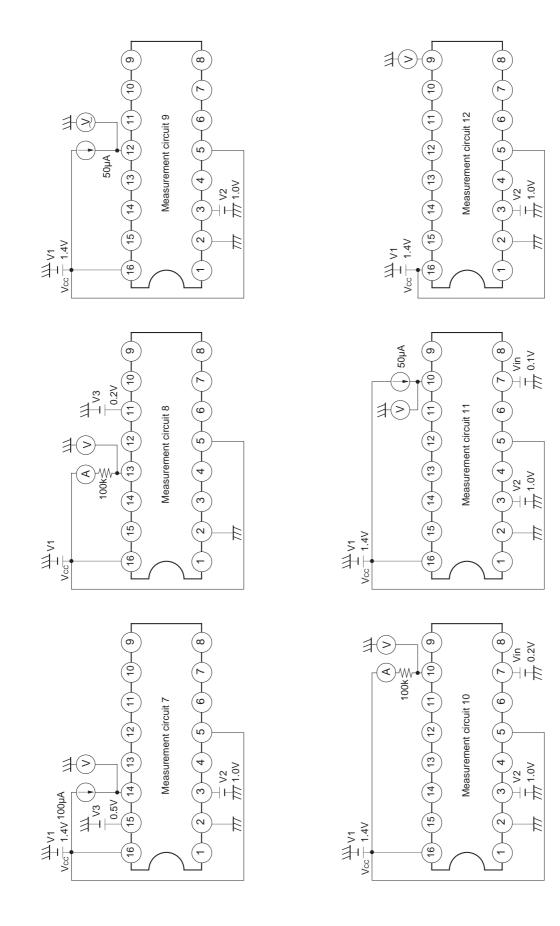
Pin No.	Symbol	Pin voltage	Equivalent circuit	Description		
7	LPF IN	0.2 V	Vcc 7 W 72 GND	Operational amplifier input.		
8	LPF OUT	0.2 V	8 72 W 72 Vcc GND	Level comparator and NRZ comparator inputs. Output for operational amplifier is connected.		
9	RSSI	0 V	9 9 F7k F7k Vcc Vcc GND	RSSI circuit output.		
10 12 13	DEV OUT NRZ OUT LVA OUT		10 12 13 GND	Level comparator, NRZ comparator and LVA comparator outputs. They are open collectors. (Applied voltage range: –0.5 V to +7.0 V)		
11	CHARGE	0 V	20k 11 • ₩ 100k GND	Controls the ON/OFF operation of the quick-charge circuit. Set this pin high to execute the quick charge. (Applied voltage range: –0.5 V to +7.0 V)		

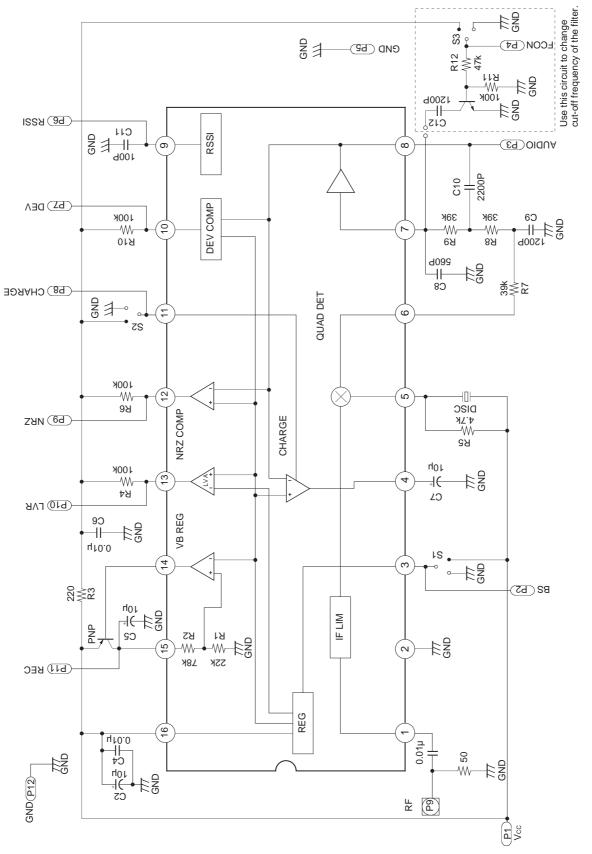
Pin No.	Symbol	Pin voltage	Equivalent circuit	Description
14	REG CONT		Vcc 14 72 GND	Output for internal constant- voltage source amplifier. Connect the base of PNP transistor. (Current capacity: 100 µA)
15	REG OUT	1.0 V	15 78k 1k 1k 322k GND	Constant-voltage source output. Controlled to maintain 1.0 V.
16	Vcc			Power supply.

ltem	Symbol	Conditions	Min.	Тур.	Max.	Unit
Current consumption	Icc	Measurement circuit 1	410	590	800	μA
		V2 = 1.0 V		000	000	μ., ί
Current consumption	Iccs	Measurement circuit 1,	_	6	20	μA
Carrent concarription		V2 = 0 V			20	μ
AM rejection ratio	AMRR	Measurement circuit 3 30k LPF	25	_	_	dB
Op amp. input bias current	IBIAS	Measurement circuit 2	—	—	100	nA
Op amp. maximum output level	Vo	Measurement circuit 4	160	—	—	mVp-p
NRZ output saturation voltage	VSATNRZ	Measurement circuit 6			0.4	V
NIC Ouput Saturation Voltage	VSAINKZ	Vin = 0.3 V		_	0.4	V
NP7 output look ourropt	ILNRZ	Measurement circuit 5		_	5.0	μA
NRZ output leak current	ILNRZ	Vin = 0.1 V	_			
NDZ byztorocja width		Measurement circuit 5		10	20	~\/
NRZ hysteresis width	Vtwnrz	Vin = 0.1 to 0.3 V	_	10	20	mV
VB output current	Ιουτ	Measurement circuit 7	100	—	—	μA
VB output saturation voltage	VSATVB	Measurement circuit 7	—	—	0.4	V
REG OUT voltage	Vreg	Output current 0 µA	0.89	0.96	1.04	V
	Vlva	Measurement circuit 8	1.00	1.05	1.10	V
LVA operating voltage	VLVA	V1 = 1.4 to 1.0 V	1.00 1.05		1.10	v
LVA output leak current	Illva	Measurement circuit 8 V1 = 1.0 V	—	—	5.0	μA
LVA output saturation voltage	VSATLVA	Measurement circuit 9	—	—	0.4	V
Detector output voltage	Vodet	Measurement circuit 3	38	50	68	mVrms
Logic input voltage high level	VTHBSV		0.9	—	_	V
Logic input voltage low level	VTLBSV		_	_	0.35	V
Limiting sensitivity	VIN (LIM)	Measurement circuit 3	_	17	24	dBµ
Level comparator output					0.4	N
saturation voltage	VSATLC	Measurement circuit 11		_	0.4	V
Level comparator output leak current					5.0	μA
		Measurement circuit 10		—		
RSSI output offset	Vorssi	Measurement circuit 12	—	135	310	mV
Mixer input resistance	RINLIM	—	1.6	2.0	2.4	kΩ
Mixer output resistance	ROUTMIX	—	1.2	1.5	1.8	kΩ
IF limiter input resistance RINLIM		—	1.2	1.5	1.8	kΩ

Electrical Characteristics (Vcc = 1.4 V, Ta = 25 °C, Fs = 455kHz, Fmod = 1.6 kHz, Fdev = 4.8 kHz, AMmod = 30 %)







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Application Circuit

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Application Note

1) Power Supply

The CXA3099N, with built-in regulator, is designed to permit stable operation at wide range of supply voltage from 1.1 to 4.0 V. Decouple the wiring to Vcc (Pin 16) as close to the pin as possible.

2) IF Limiter Amplifier

The gain of this IF limiter amplifier is approximately 100 dB. Take notice of the following points in making connection to the IF limiter amplifier input pin (Pin 1).

- a) Wiring to the IF limiter amplifier input (Pin 1) should be as short as possible.
- b) As the IF limiter amplifier output appears at QUAD (Pin 5), wiring to the ceramic discriminator connected to QUAD should be as short as possible to reduce the interference with the mixer output and IF limiter amplifier input.

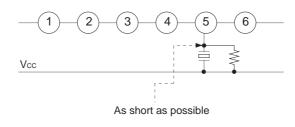


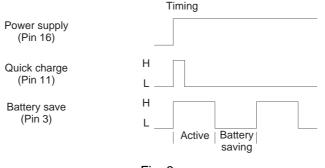
Fig. 2

3) Quick Charge

In order to hasten the rising time from when power is turned on, the CXA3099N features a quick charge circuit. Therefore, the quick charge circuit eliminates the need to insert a capacitor between the detector output and the LPF as is the case with conventional ICs, but capacitor should be connected to Pin 4 to determine the average signal level during steady-state reception. The capacitance value connected to Pin 4 should be chosen such that the voltage does not vary much due to discharge during battery saving.

Connect a signal for controlling the quick charge circuit to Pin 11. Setting this pin high enables the quick charge mode, and setting this pin low enables the steady-state reception mode. Quick charge is used when the power supply is turned on. The battery saving must be set high at the time.

Connect Pin 14 to GND when quick charge is not being used.



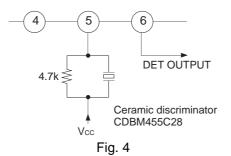


4) Detector

The detector is of quadrature type. To perform phase shift, connect a ceramic discriminator to Pin 5. The phase shifting capacitor for the quadrature detector is incorporated. The FM (FSK) signal with the demodulated detector will be output to DET OUT (Pin 6) through the internal primary LPF.

DET OUT output impedance is 200 Ω or less. The DET OUT output is the anti-phase output to NRZ OUT.

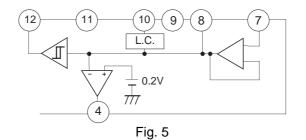
The CDBM455C28 (MURATA MFG. CO., LTD.) ceramic discriminator is recommended for the CXA3099N.



5) Filter Buffer, Level Comparator and NRZ Comparator

An operational amplifier for LPF is built in this IC.

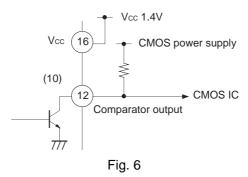
It is connected internally to the NRZ comparator, level comparator and quick charge circuit.



Using the operational amplifier of Pins 7 and 8 to construct an LPF, remove noise from the demodulated signal and input the signal to the above three circuits.

The level comparator and the NRZ comparator shape waveform of this input signal and output it as a square wave. The comparator output stage is for open collector.

Thus, if the CPU is of CMOS type and the supply voltage is different, a direct interface as illustrated in the figure below can be implemented.



6) REG CONT

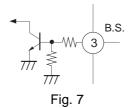
Controls the base bias of the external transistors.

7) LVA OUT

This pin goes high (open) when the supply voltage becomes low. Since the output is an open collector, it can be used to directly drive CMOS device. The setting voltage of the LVA is 1.05 V (typ.), and it possesses a hysteresis with respect to the supply voltage. The hysteresis width is 50 mV (typ.).

8) B.S.

Operation of the CXA3099N can be halted by setting this pin low. This pin can be connected directly to CMOS device. The current consumption for battery saving is $20 \ \mu$ A or less (at 1.4 V).



9) M-ary (M = 2- or 4-level) FSK Demodulation System

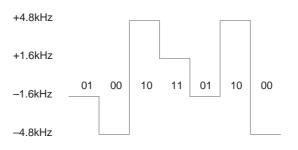
POS

NEG

Polarity discrimination output and MSB comparator output are used to demodulate the 4-level waveform shown below.

[4-level FSK demodulating waveform]

[NRZ OUT] Polarity discrimination output

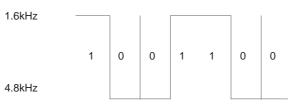


(When the input frequency is higher than the local frequency)

0 0 1 1 0 1 0

The polarity can be inverted by setting the local frequency higher than the input frequency.

[L.C. OUT] MSB comparator output



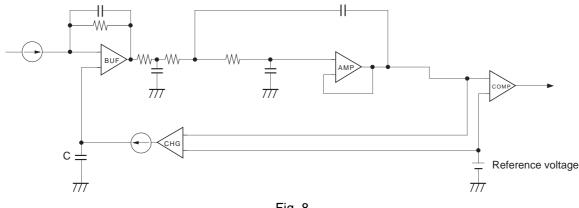
The 4-level FSK demodulating data is divided into an NRZ OUT and L.C. OUT shown above. Here, the NRZ OUT corresponds to a conventional NRZ comparator output. The L.C. OUT is made comparing the demodulated waveform amplitude to the IC internal reference voltage levels. When the threshold value of L.C. OUT is not appropriate to the detector output, the resistance value on Pin 5 should be adjusted for the detector output level adjustment.

For the 2-level FSK demodulation, it corresponds to a conventional NRZ comparator output.

10) Principle of Quick Charge Operation

BUF in Fig. 8 is the detector buffer amplifier, and AMP is an operational amplifier to construct an LPF. COMP is the level comparator or the NRZ comparator. The CXA3099N has a feedback loop from the comparator input to the input circuit of the detector output buffer. This equalizes the average value of the comparator input voltage to the reference voltage, with the quick charge circuit of CHG being set in the feedback loop. Switching the current of the quick charge circuit enables reduction of the rise time.

In this block, CHG is a comparator which compares input voltages and outputs a current based on this comparison. The current on CHG is switched between high and low at Pin 11. When the power is turned on, switch the current to high to increase the charge current at C in Fig. 8 and shorten the time constant. During steady-state reception mode, switch the current to low, lengthening the charge time constant and allowing for stable data retrieval.

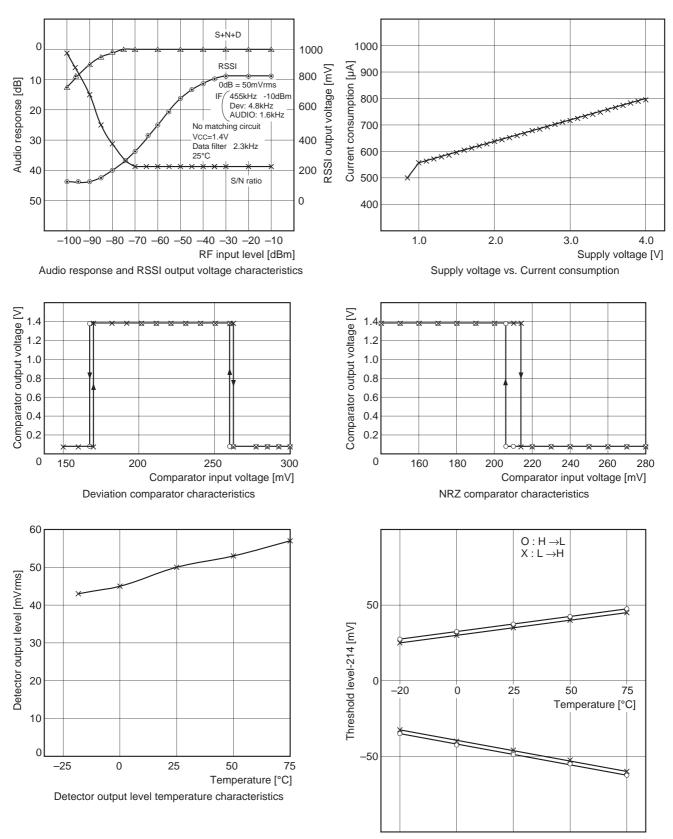




11) S Curve Characteristics

Even if the IF IN input signal frequency is deviated, the feedback is applied to the DET OUT operating point so as to match it to the comparator reference voltage by the quick charge operation shown in Fig. 8. Therefore, this feedback must be halted in order to evaluate the S curve characteristics.

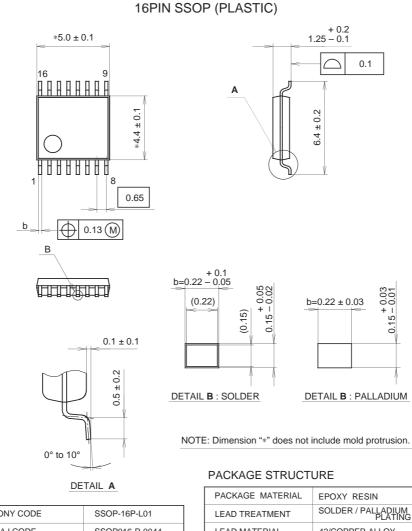
To execute the evaluation, measure the average voltage on Pin 8 first and input this voltage to Pin 4 from the external power supply.



Example of Representative Characteristics

Level comparator temperature vs.Threshold level

Package Outline Unit : mm



SONY CODE	SSOP-16P-L01
EIAJ CODE	SSOP016-P-0044
JEDEC CODE	

PACKAGE MATERIAL	EPOXY RESIN					
LEAD TREATMENT	SOLDER / PALLADIUM PLATING					
LEAD MATERIAL	42/COPPER ALLOY					
PACKAGE MASS	0.1g					

NOTE : PALLADIUM PLATING This product uses S-PdPPF (Sony Spec.-Palladium Pre-Plated Lead Frame).